

30V High Side Over Voltage Protector

Features

- 30V standoff voltage
- Fixed 6.0V protection voltage
- Integrated OTP
- Environment Temperature: -40°C~85°C
- Maximum load Current 2A
- Typical equivalent on-resistance 110mΩ
- Input OVP with 0.1us reaction time
- SOT-23-3, SOT23-6 package

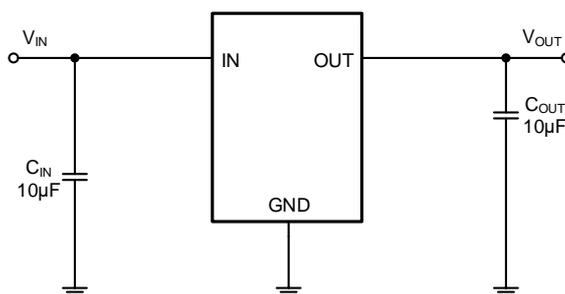
Applications

- All electronic devices with input DC power plug
- E-Cigarette
- Car Camera
- Cellphone

General Description

HM4803B is a high voltage 30V over voltage protector (OVP) which has a low on resistance, by only change the external connecting. It can be used as an OVP device or a high voltage switch. HM4803B consists of a charge pump, a configurable power MOSFET, a voltage reference, a gate driver and some logics and protection modules. HM4803B can react to an input surge very fast and shut off the switch in less than 0.1us. HM4803B is available in SOT-23-3, SOT23-6 package.

Typical Application Circuit

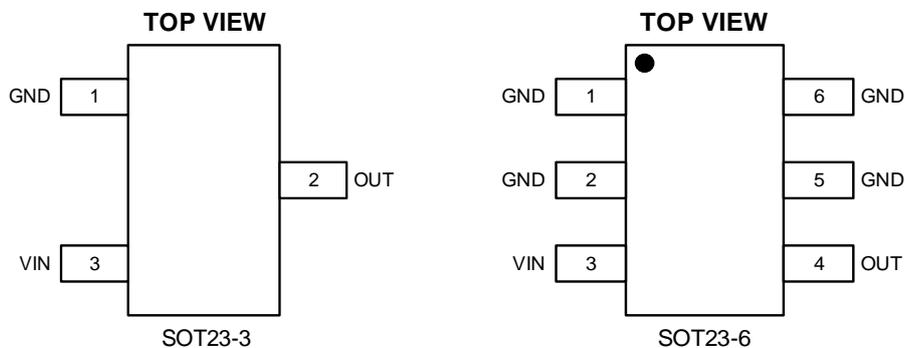


HM4803B fixed version application circuit

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Pin Description

Pin Configuration



HM4803B Top Marking: mAYLL_ [device code: mA, Y=year code, LL= lot number code)

HM4803B Top Marking: mBYLL_ [device code: mB, Y=year code, LL= lot number code)

Pin Description

SOT23-3 Pin No.	SOT23-6 Pin No.	Name	Function
2	4	OUT	Output voltage (V_{OUT}) pin for the regulator
3	3	VIN	Input voltage (V_{IN}) pin for the regulator.
1	1/2/5/6	GND	Ground pin

Order Information ⁽¹⁾

Marking	Part No.	Model	Description	Package	T/R Qty
mAYLL	70702302	HM4803B	HM4803B OVP IC, VIN 2.5-30V, OVP fixed 6.0V, 2A, SOT23-3	SOT23-3	3000PCS
mBYLL	70702301	HM4803B	HM4803B OVP IC, VIN 2.5-30V, OVP fixed 6.0V, 2A, SOT23-6	SOT23-6	3000PCS

Note (1): All H&M Semi parts are Pb-Free and adhere to the RoHS directive.

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Specifications

Absolute Maximum Ratings ^{(1) (2)}

Item	Min	Max	Unit
Maximum V _{IN} voltage	-0.3	30	V
Power dissipation ⁽³⁾	Internally Limited		
Operating junction temperature, T _{J(MAX)}		150	°C
Storage temperature, T _{stg}	-65	150	°C
Lead Temperature (Soldering, 10sec.)		260	°C

Note (1): Exceeding these ratings may damage the device.

Note (2): The device is not guaranteed to function outside of its operating conditions.

Note (3): The maximum allowable power dissipation is a function of the maximum junction temperature, T_{J(MAX)}, the junction-to-ambient thermal resistance, R_{θJA}, and the ambient temperature, T_A. The maximum allowable power dissipation at any ambient temperature is calculated using: P_{D(MAX)} = (T_{J(MAX)} - T_A)/R_{θJA}. Exceeding the maximum allowable power dissipation causes excessive die temperature, and the regulator goes into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage. Thermal shutdown engages at T_J=160°C (typical) and disengages at T_J= 130°C (typical).

ESD Ratings

Item	Description	Value	Unit
V _(ESD-HBM)	Human Body Model (HBM) ANSI/ESDA/JEDEC JS-001-2014 Classification, Class: 2	±2000	V
V _(ESD-CDM)	Charged Device Mode (CDM) ANSI/ESDA/JEDEC JS-002-2014 Classification, Class: C0b	±200	V
I _{LATCH-UP}	JEDEC STANDARD NO.78E APRIL 2016 Temperature Classification, Class: I	±150	mA

Recommended Operating Conditions

Item	Min	Max	Unit
Operating junction temperature ⁽¹⁾	-40	125	°C
Operating temperature range	-40	85	°C
Input voltage V _{IN}	2.5	6	V

Note (1): All limits specified at room temperature (T_A = 25°C) unless otherwise specified. All room temperature limits are 100% production tested. All limits at temperature extremes are ensured through correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).

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Thermal Information

Item	Description	SOT23 3 Pin	SOT23 6 Pin	Unit
R _{θJA}	Junction-to-ambient thermal resistance ⁽¹⁾⁽²⁾	208	180	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	112	130	°C/W
R _{θJB}	Junction-to-board thermal resistance	56	45	°C/W
ψ _{JT}	Junction-to-top characterization parameter	9.2	35	°C/W
ψ _{JB}	Junction-to-board characterization parameter	52	45	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

Note (1): The package thermal impedance is calculated in accordance to JESD 51-7.

Note (2): Thermal Resistances were simulated on a 4-layer, JEDEC board

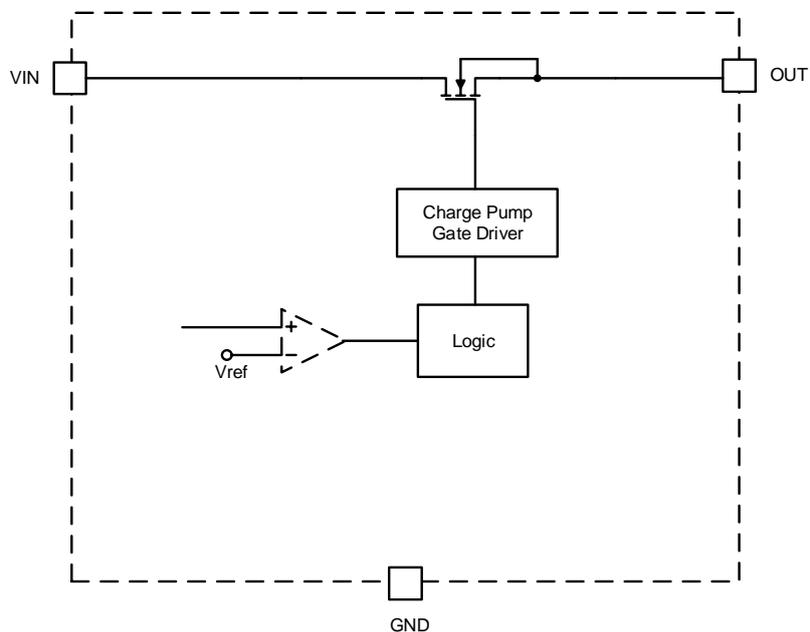
Electrical Characteristics

V_{IN} =5V, T_A=25°C, unless otherwise noted.

Parameter	Test Conditions	Min	Typ.	Max	Units
Input Voltage		2.5		5.9	V
UVLO	Hys=260mV		2.4		V
OVP			6.0		V
OVP Range		2.5		30	V
Ron	VCC=5V, Iout=1A	-	110		mΩ
Iq	Standby current, IN and Vcc < OVP voltage		150		uA
Isd	Shutdown current		10		μA
Thermal Shutdown	Rising, Hys=50°C		135		°C

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Block Diagram



HM4803B Block Diagram

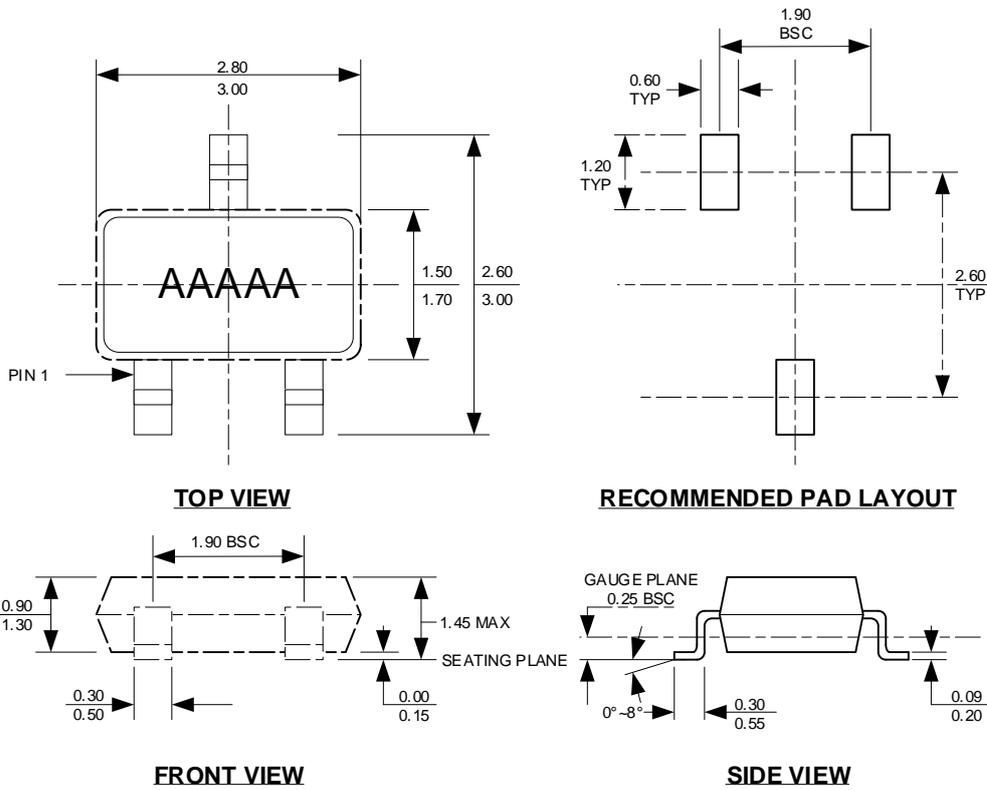
Detailed Description

HM4803B can disconnect the systems from its output pin (OUT) in case wrong input operating conditions are detected. The system is positive overvoltage protected up to 30V. The internal OVLO is 6.0V. HM4803B also has internal over temperature protect (OTP) function and it can monitor chip temperature to protect the device.

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Package Description

SOT23-3



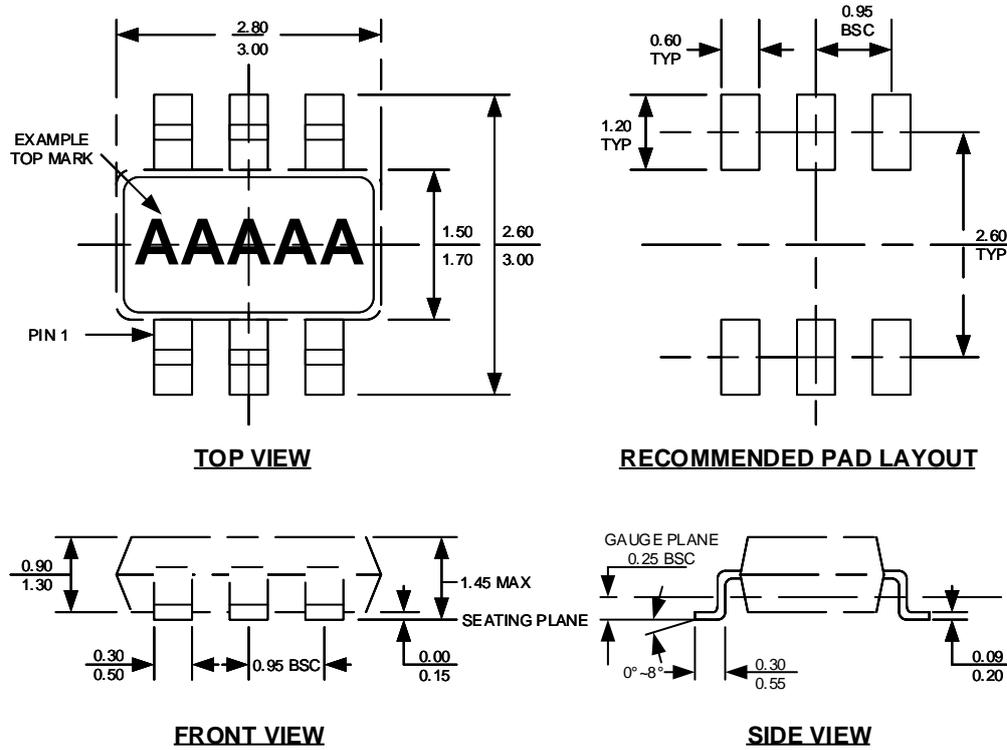
NOTE:

1. CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
2. PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
3. PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
4. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
5. DRAWING CONFORMS TO JEDEC MS-012, VARIATION BA.
6. DRAWING IS NOT TO SCALE.

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Package Description

SOT23-6



NOTE:

1. CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
2. PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
3. PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
4. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
5. DRAWING CONFORMS TO JEDEC MS-012, VARIATION BA.
6. DRAWING IS NOT TO SCALE.